

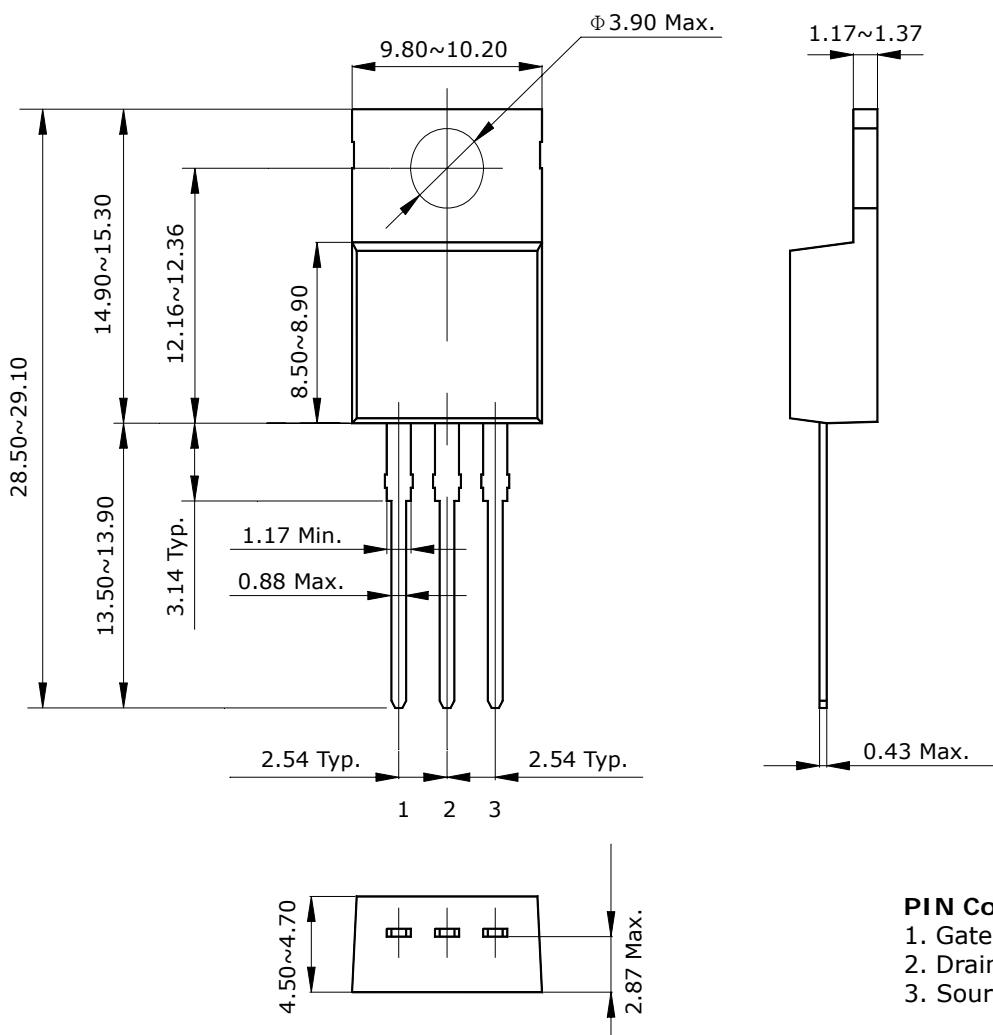
## SWITCHING REGULATOR APPLICATIONS

**Features**

- High Voltage:  $BV_{DSS}=60V$ (Min.)
- Low  $C_{rss}$  :  $C_{rss}=84pF$ (Typ.)
- Low gate charge :  $Qg=26.7nC$ (Typ.)
- Low  $R_{DS(on)}$  :  $R_{DS(on)}=25m\Omega$ (Max.)

**Ordering Information**

Type NO.	Marking	Package Code
STK5006P	STK5006	TO-220AB-3L

**Outline Dimensions**
**unit : mm**


**Absolute maximum ratings (Tc=25°C)**

Characteristic Symbol		Rating	Unit
Drain-Source voltage	V <sub>DSS</sub>	60	V
Gate-Source voltage	V <sub>GSS</sub>	±20	V
Continuous Drain current (Tc=25°C)	I <sub>D</sub> 50		A
Continuous Drain current (Tc=100°C)	I <sub>D</sub> 35.4		A
Drain Current-Pulsed ①	I <sub>DM</sub> 200		A
Power Dissipation (Tc=25°C)	P <sub>D</sub> 120		W
Single Pulsed Avalanche Energy ②	E <sub>AS</sub> 490		mJ
Avalanche current ①	I <sub>AR</sub> 50		A
Repetitive Avalanche Energy ①	E <sub>AR</sub> 12		mJ
Junction temperature	T <sub>J</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-55~175	

**Thermal Resistance**

Characteristic Symbol		Typ.	Max	Units
Junction to Case	R <sub>th(J-C)</sub>	-	1.24	°C/W
Junction to Ambient	R <sub>th(J-a)</sub>	-	62.5	

## Electrical Characteristics (Tc=25°C)

Characteristic Symbol		Test Condition	Min.	Typ.	Max.	Unit
Drain-Source breakdown voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0	60 -		-	V
Gate-Threshold voltage	V <sub>GS(th)</sub>	I <sub>D</sub> =250μA, V <sub>DS</sub> = V <sub>GS</sub>	2.0 -		4.0	V
Drain-source leakage current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V -		-	1	μA
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V	--		±100	nA
Drain-Source on-resistance ④	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =25A -		18	22	mΩ
Forward transfer admittance ④	g <sub>fs</sub>	V <sub>DS</sub> =25V, I <sub>D</sub> =25A -		22	-	S
Input capacitance	C <sub>iss</sub> -	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		1289	1675	pF
Output capacitance	C <sub>oss</sub>		-	445	580	
Reverse transfer capacitance	C <sub>rss</sub>		- 84		110	
Turn-on delay time	t <sub>d(on)</sub>	V <sub>DD</sub> =30V, I <sub>D</sub> =25A R <sub>G</sub> =25Ω	-	15	40	ns
Rise time	t <sub>r</sub>		-	105	220	
Turn-off delay time	t <sub>d(off)</sub>		-	80	180	
Fall time	t <sub>f</sub>		- 85		180	
Total gate charge	Q <sub>g</sub> -	V <sub>DS</sub> =48V, V <sub>GS</sub> =10V, I <sub>D</sub> =50A		26.7	34	nC
Gate-source charge	Q <sub>gs</sub> -			5.0	-	
Gate-drain("Miller")charge Q	g <sub>d</sub>		- 10.	2	-	

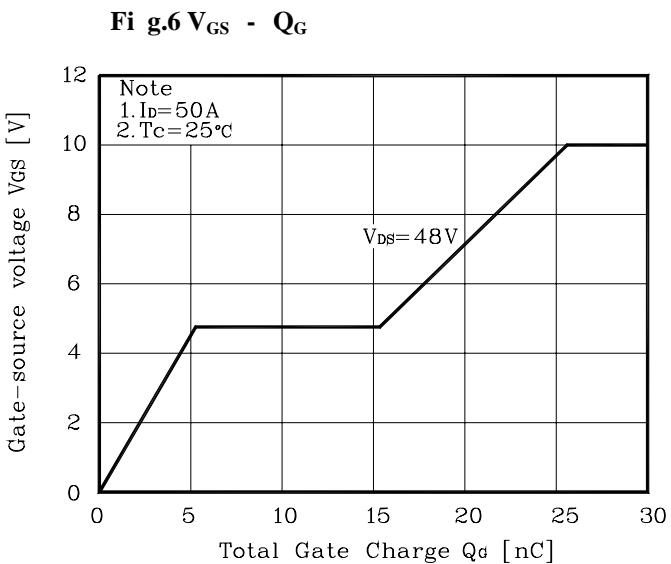
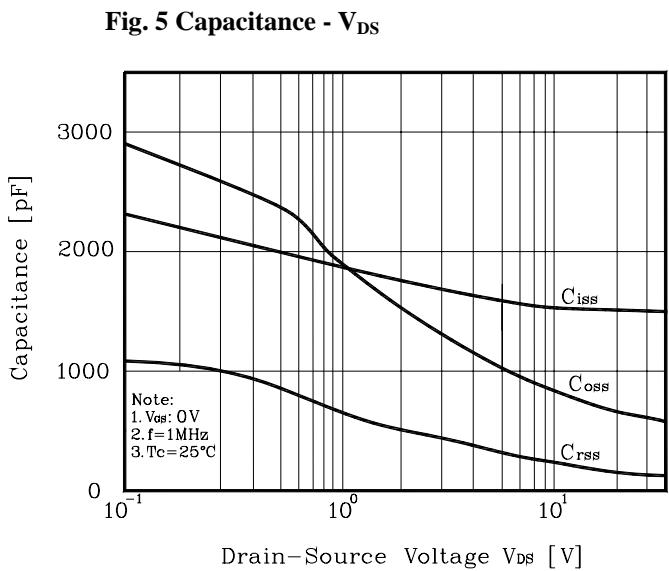
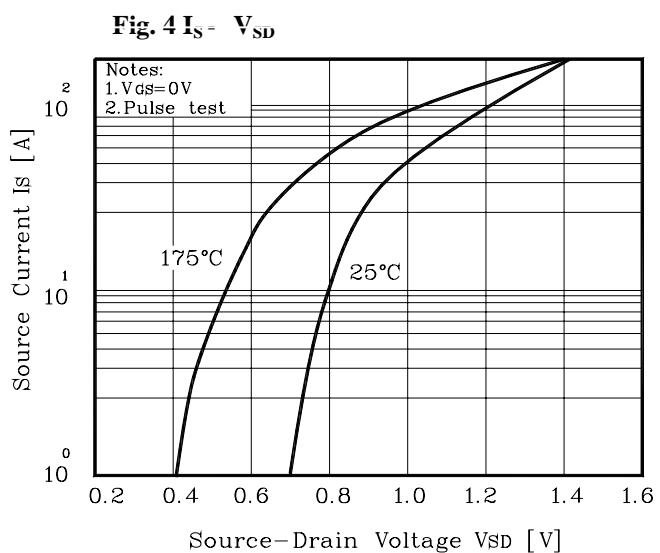
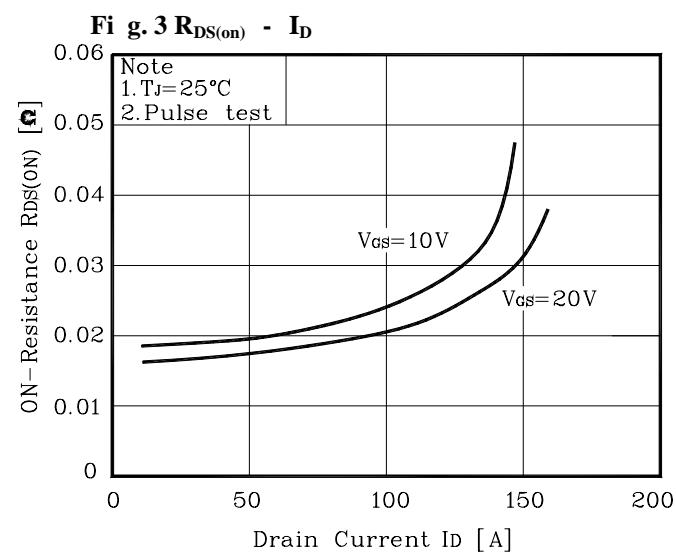
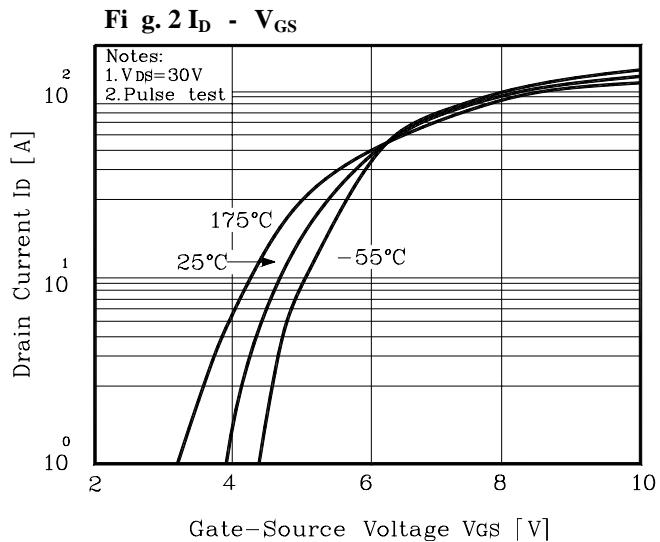
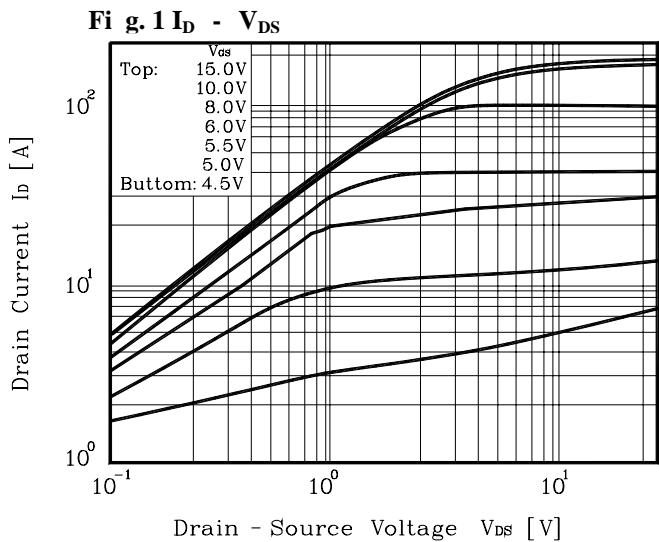
## Source-Drain Diode Ratings and Characteristics (Tc=25°C)

Characteristic Symbol		Test Condition	Min	Typ	Max	Units
Continuous source current	I <sub>S</sub>	Integral reverse diode in the MOSFET	-	-	50	A
Pulsed-source current ①	I <sub>SM</sub>		--		200	
Diode forward voltage ④	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =50A -		-	1.5	V
Reverse recovery time	t <sub>rr</sub>	I <sub>s</sub> =50A di <sub>f</sub> /dt=100A/us	-	45	-	ns
Reverse recovery charge	Q <sub>rr</sub>		- 70		-	uC

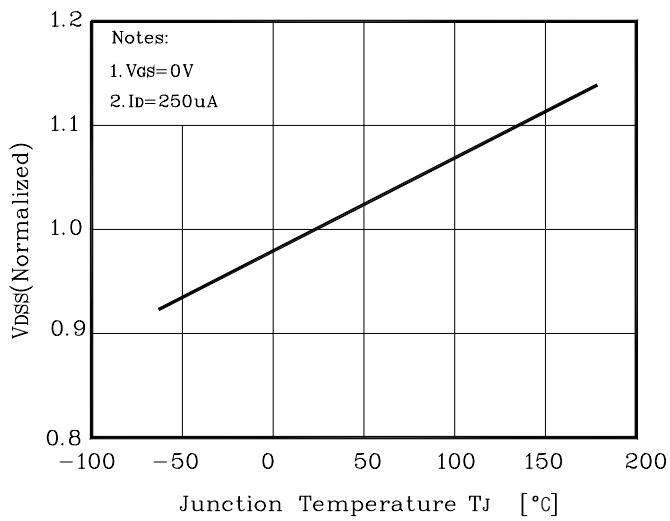
Note :

- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- ② L=230μH I<sub>AS</sub>=50A, V<sub>DD</sub>=25V, R<sub>G</sub>=25Ω , starting T<sub>j</sub>=25 °C
- ③ I<sub>S</sub> ≤ 50A, di/dt≤ 300A/us, V<sub>DD</sub>≤ BV<sub>DSS</sub>, starting T<sub>j</sub>=25 °C
- ④ Pulse Test : Pulse Width < 30 0us, Duty cycle≤ 2%
- ⑤ Essentially independent of operating temperature

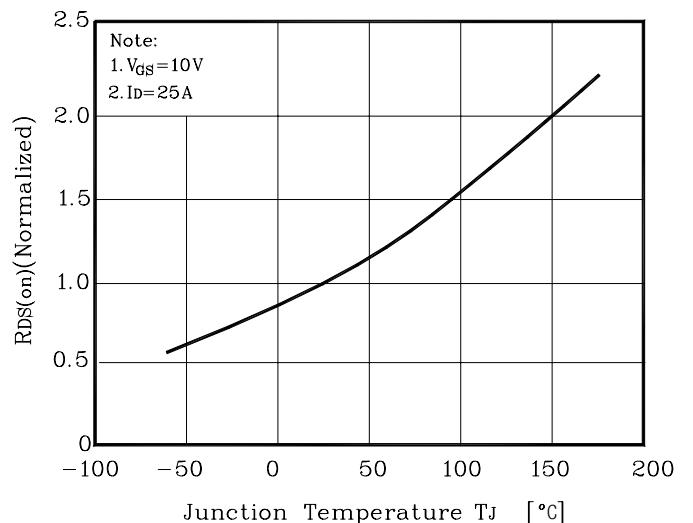
## Electrical Characteristic Curves



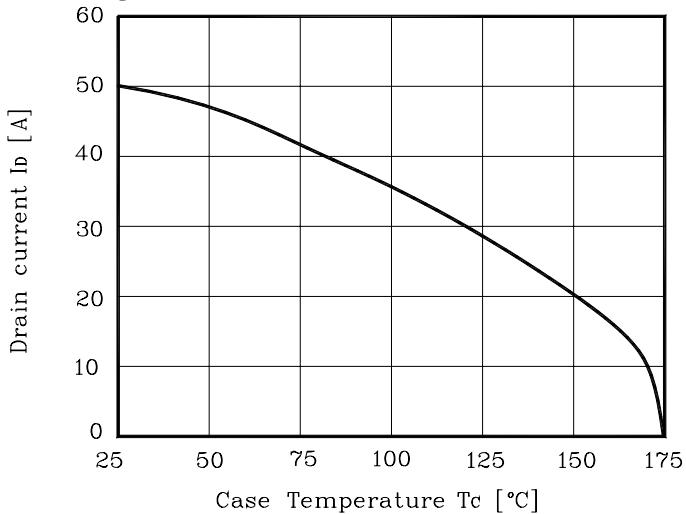
**Fig. 7  $V_{DSS}$  -  $T_J$**



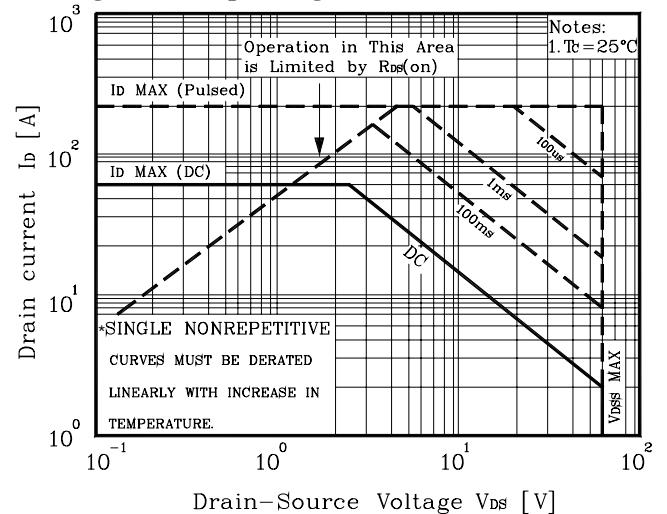
**Fig.8  $R_{DS(on)}$  -  $T_J$**



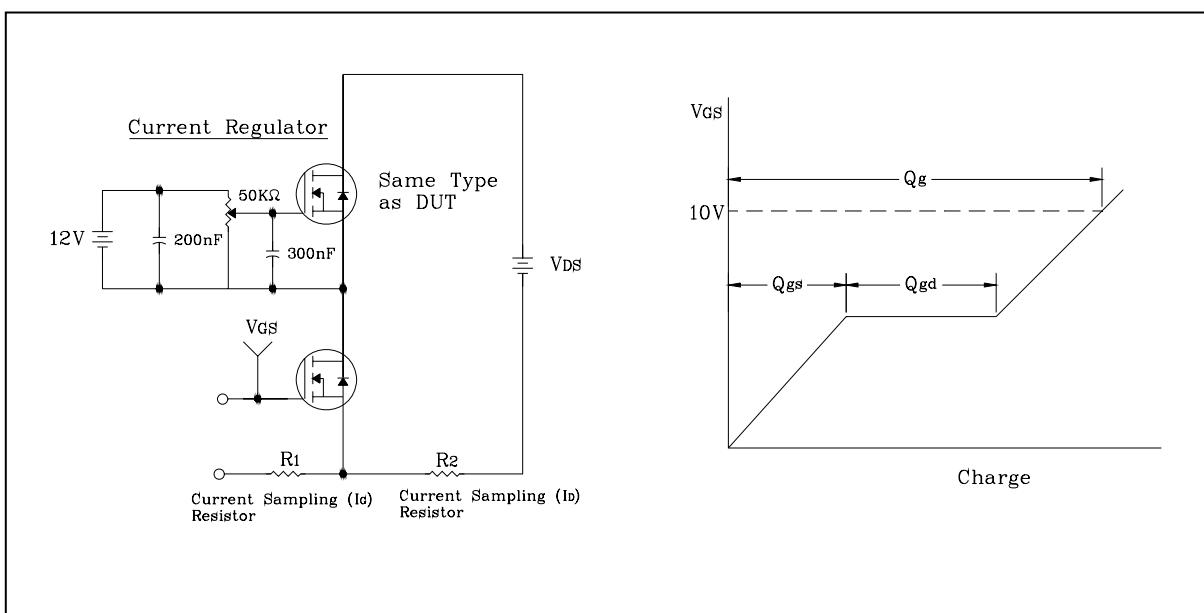
**Fig. 9  $I_D$  -  $T_C$**



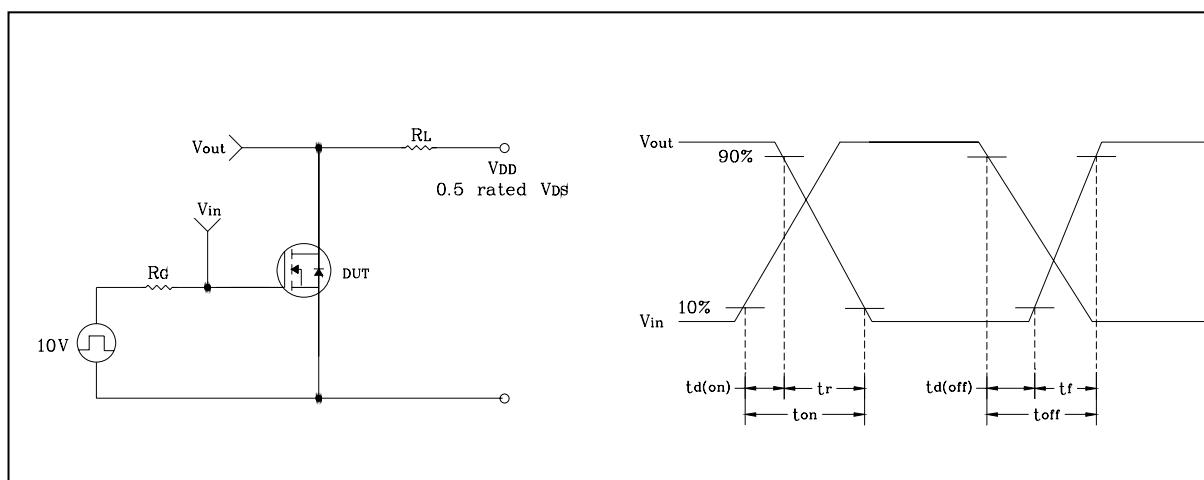
**Fig. 10 Safe Operating Area**



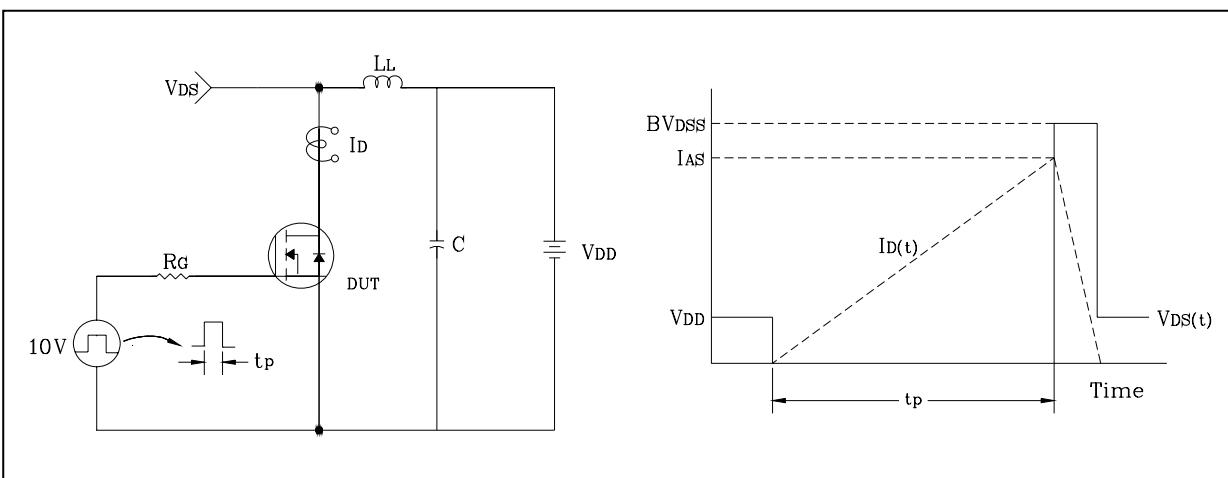
**Fig. 10 Gate Charge Test Circuit & Waveform**



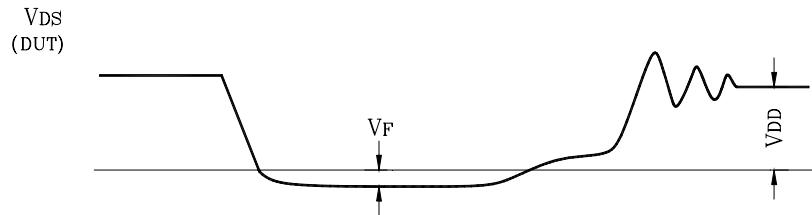
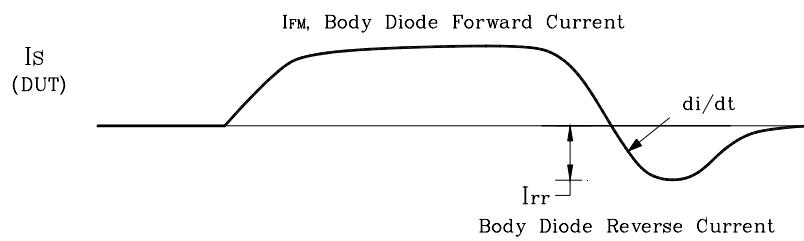
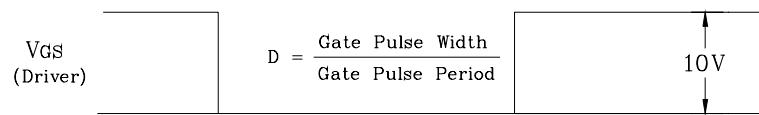
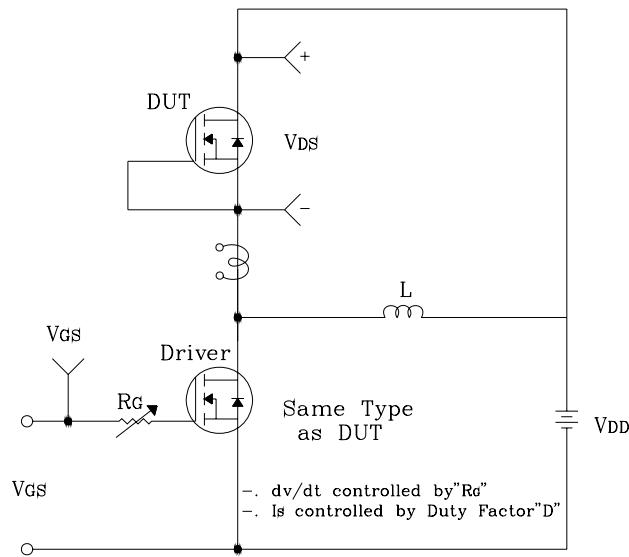
**Fig. 11 Resistive Switching Test Circuit & Waveform**



**Fig. 12 E<sub>AS</sub> Test Circuit & Waveform**



**Fig. 13 Diode Reverse Recovery Time Test Circuit & Waveform**



**The AUK Corp. products are intended for the use as components in general electronic equipment (Office and communication equipment, measuring equipment, home appliance, etc.).**

**Please make sure that you consult with us before you use these AUK Corp. products in equipments which require high quality and / or reliability, and in equipments which could have major impact to the welfare of human life(atomic energy control, airplane, spaceship, transportation, combustion control, all types of safety device, etc.). AUK Corp. cannot accept liability to any damage which may occur in case these AUK Corp. products were used in the mentioned equipments without prior consultation with AUK Corp..**

**Specifications mentioned in this publication are subject to change without notice.**